

# Nonlinear response and crosstalk of strongly driven silicon spin qubits

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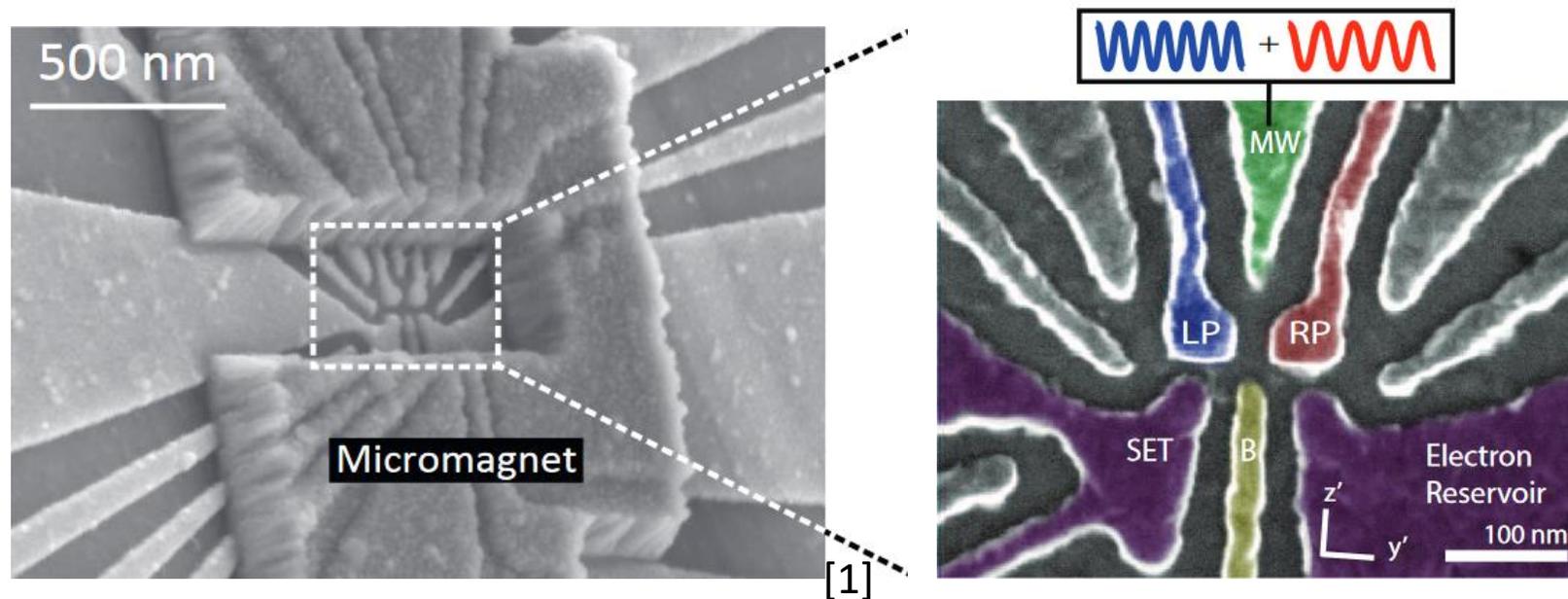
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**Spin Journal Club**

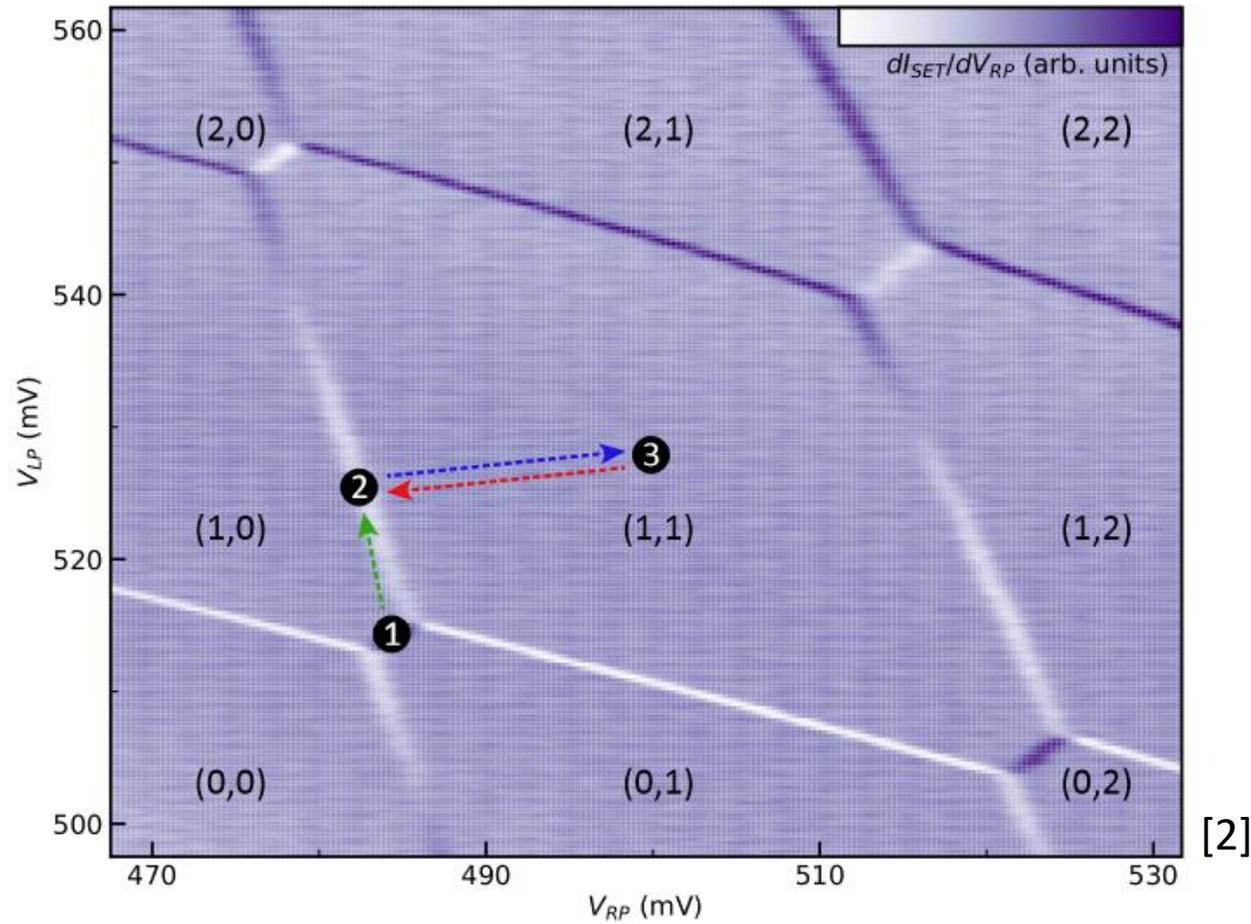
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# Nonlinear response and crosstalk of strongly driven silicon spin qubits

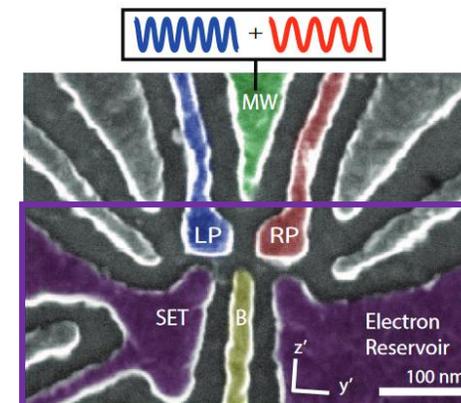
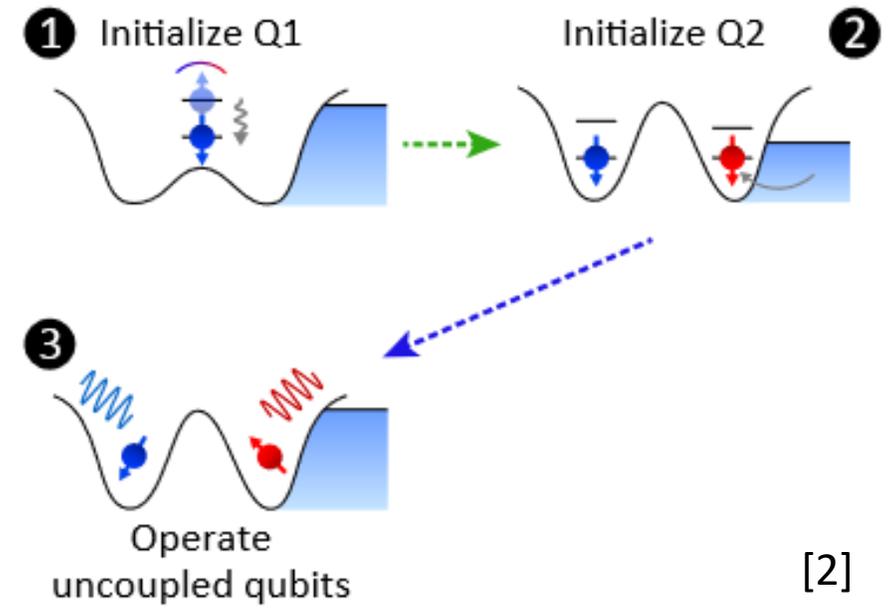
- Scaling: Multiplexed driving field to address individual, spectrally separated qubits
- Challenge: Maintaining high fidelity operations if qubit dynamics are affected by off-resonant tones
- Here: Experimental characterization of crosstalk for single-qubit rotations
- System: Electron QD in  $^{28}\text{Si}/\text{SiGe}$  QW, with Co micromagnet placed on top for «synthetic» SOI



# Initialization, readout and control

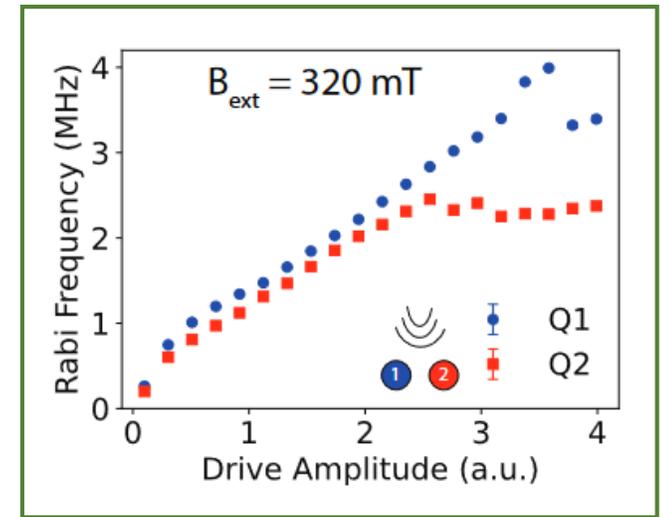


- Readout: Spin-selective tunneling to electron reservoir



# Nonlinear Rabi frequency scaling (I)

- Gate-defined QDs in Si: EDSR mediated by orbit-like or valley-like hybridized states
- In either case, linear scaling of Rabi frequencies with drive amplitude is expected
- Driving tones for either Qubit 1 or 2 are applied (not simultaneously):



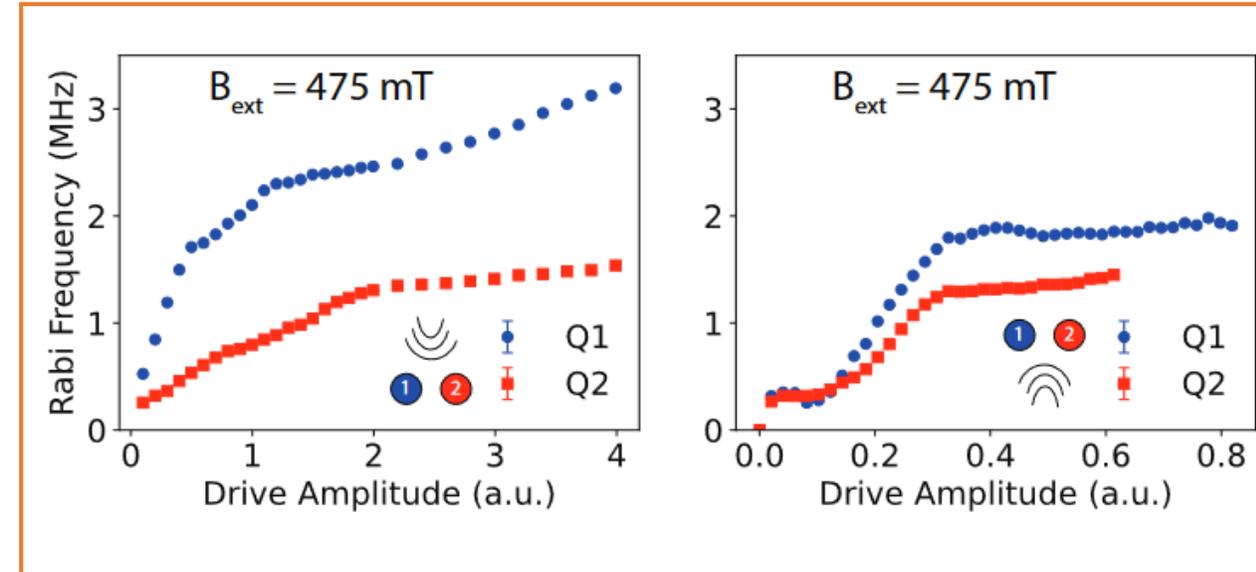
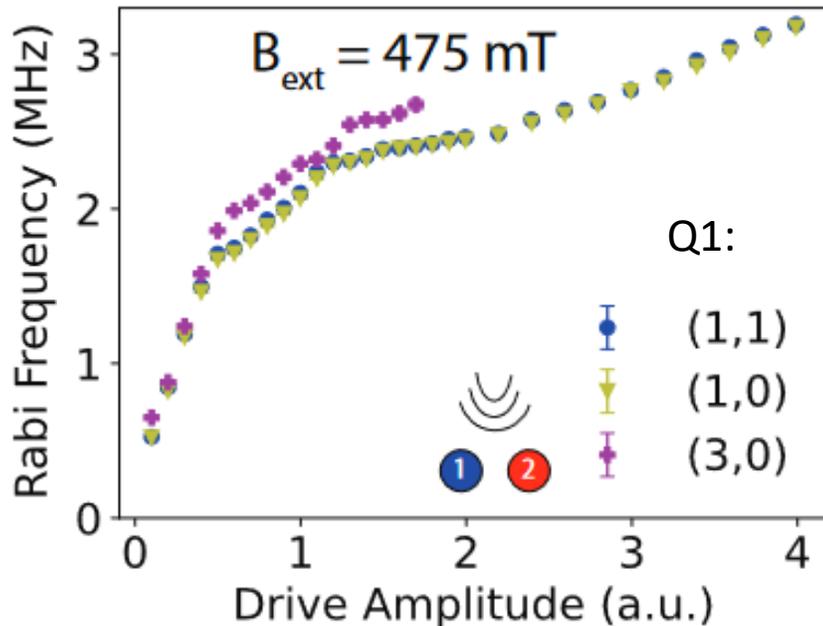
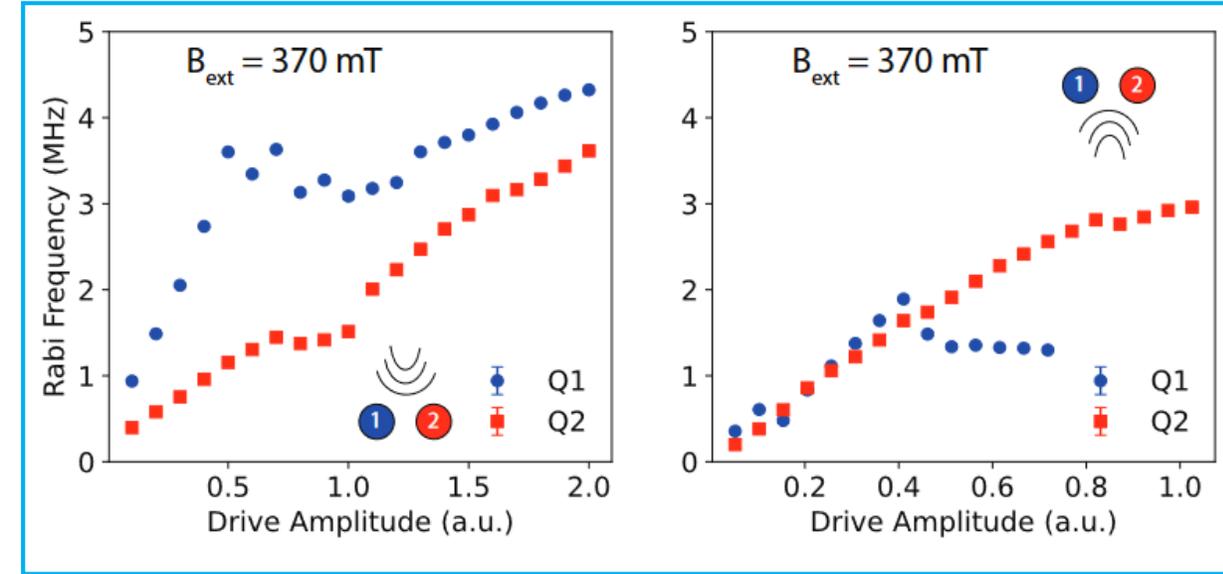
→ Nonlinearity distinct to each qubit frequency

→ Rule out

- Micromagnet gradient: nearly constant over QD length scale
- Resonance frequency shift: Would increase  $f_{Rabi}$

# Nonlinear Rabi frequency scaling (II)

- Shape of nonlinearity changes with  $B_{ext}$  and driving gate
- Change of Q2 occupancy only weakly affects Rabi scaling of Q1:

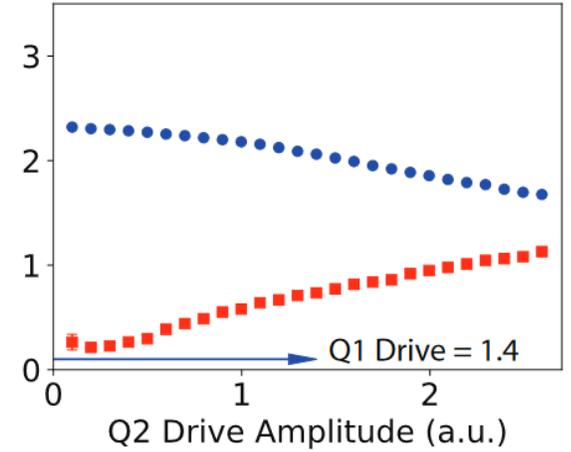
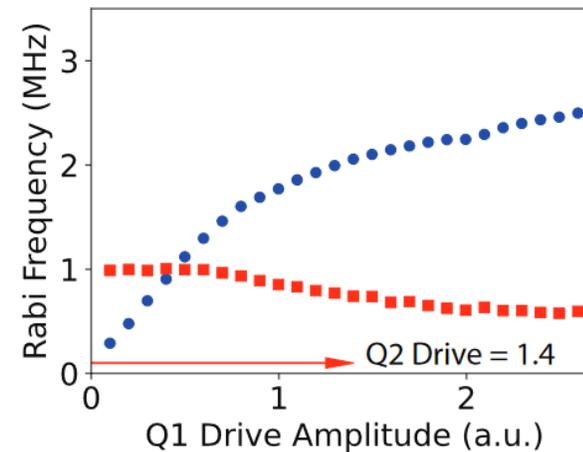
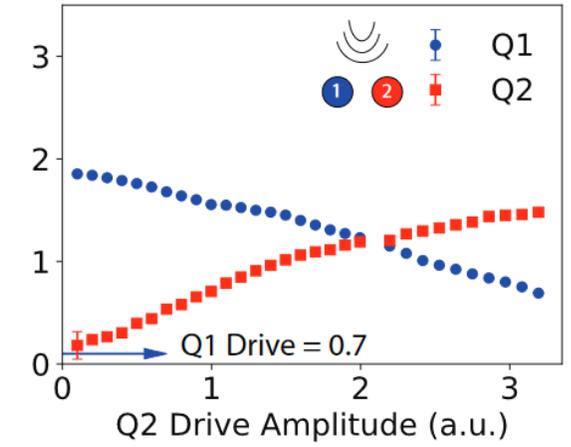
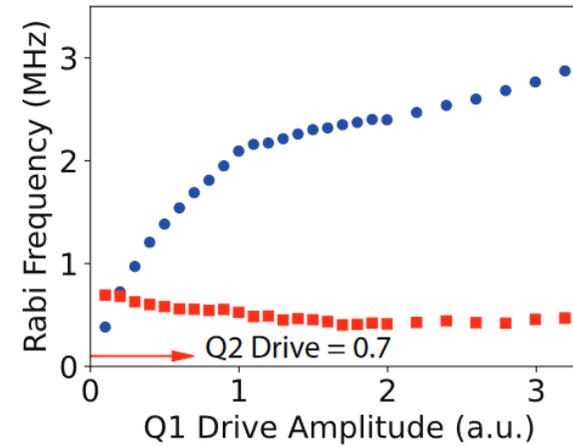


# Single-qubit crosstalk

- Both qubit driving tones applied simultaneously; one of them at a fixed drive amplitude (arrow)

- Effect on  $f_{Rabi}$  is stronger when resonant tone amplitude is smaller than off-resonant tone (atleast for Q1 this seems to be the case...)

→ Crosstalk would become more severe as single-qubit operations are more densely multiplexed



# Phenomenological model (I)

$$H(t) = H_0 - \frac{E_Z}{2} \sigma_z + b'_{SL} \hat{x} \vec{n} \cdot \vec{\sigma} + E'_{ac}(t) \hat{x}$$

Orbital and valley degrees of freedom of charge state

Zeeman energy  $E_Z = g\mu_B B_{tot}$ ,  
with  $B_{tot}$  along  $\sigma_z$  spin quantization axis

$b'_{SL} = \frac{1}{2} g\mu_B |\vec{b}_{SL}|$   
With  $|\vec{b}_{SL}|$  the magnitude of the  
magnetic field along driving axis (x),  
and  $\vec{n} = (0, \cos \theta, \sin \theta)^T$   
( $\theta$ : angle of gradient relative to  $\sigma_y$ )

Electric drive:  $E'_{ac}(t) = e \sum_k E_{ac,k} \sin(\omega_k t)$

Harmonic confinement:  $\bar{H}_0 = \hbar\omega_0(\hat{a}^\dagger \hat{a} + \frac{1}{2}) \rightarrow \Omega_{rabi} \propto E_{ac}$  (does not explain nonlinearity)

Anharmonic confinement:  $H(t) = -\frac{\Delta_0}{2} \tau_z + E'_{ac} \sin(\omega t) \hat{x} - \frac{E_Z}{2} \sigma_z + b'_{SL} \hat{x} \sigma_x$  ( $\Delta_0$ : energy splitting between ground/excited state, e.g. orbital-mediated or valley-mediated; acted on by set of Pauli operators  $\{\tau_i\}$ )

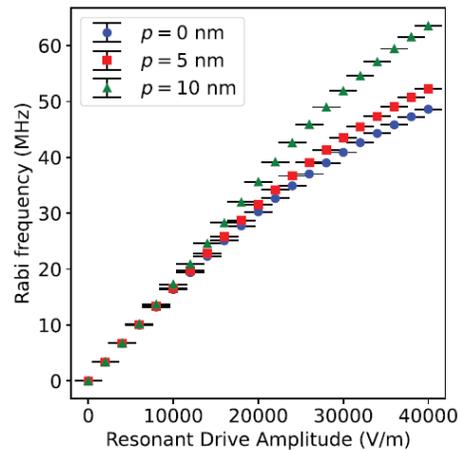
Eigenstates  $|VO_0\rangle$  and  $|VO_1\rangle$  may contain transverse/longitudinal terms:  $\hat{x} = r\tau_x - p\tau_z$  (r: dipole transition element; p: influence of asymmetric confinement)

# Phenomenological model (II)

Anharmonic confinement:  $H(t) = -\frac{\Delta_0}{2}\tau_z + E'_{ac} \sin(\omega t)\hat{x} - \frac{E_Z}{2}\sigma_z + b'_{SL}\hat{x}\sigma_x$  ( $\Delta_0$ : energy splitting between ground/excited state, e.g. orbital-mediated or valley-mediated; acted on by set of Pauli operators  $\{\tau_i\}$ )

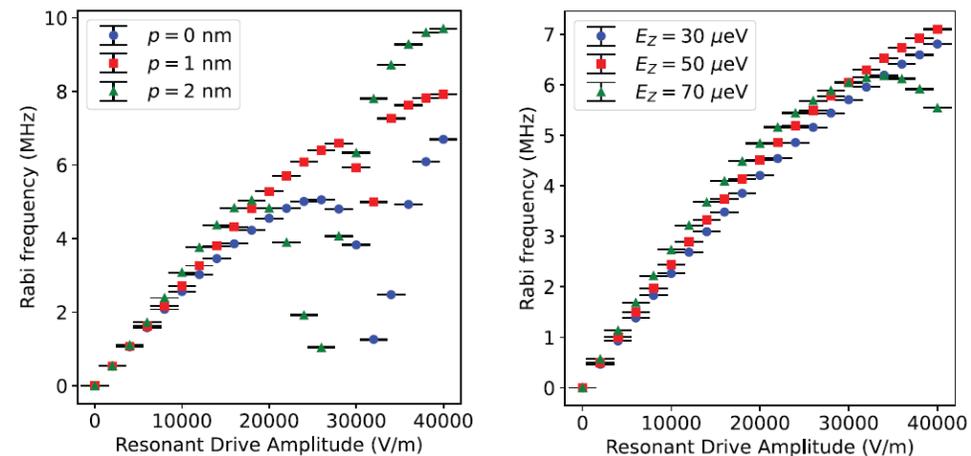
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Orbital-mediated:



$\Delta_0 = 1 \text{ meV}$ ,  $r = 20/\sqrt{2} \text{ nm}$ , and  $E_Z = 60 \mu\text{eV}$

Valley-mediated:



$\Delta_0 = 150 \mu\text{eV}$ ,  $r = 2 \text{ nm}$ , and  $E_Z = 60 \mu\text{eV}$ .

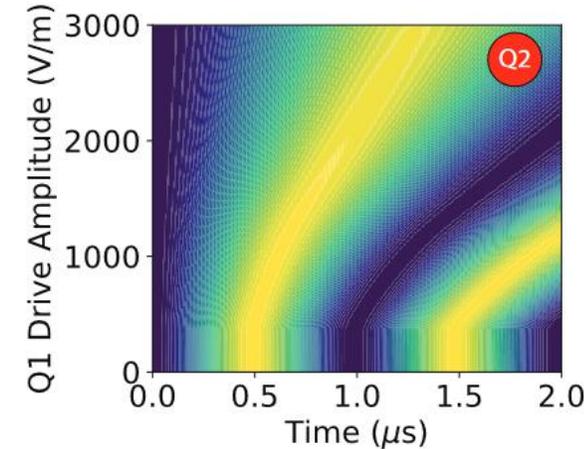
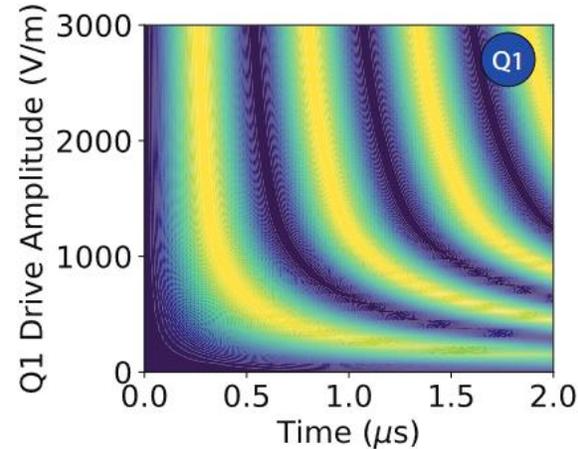
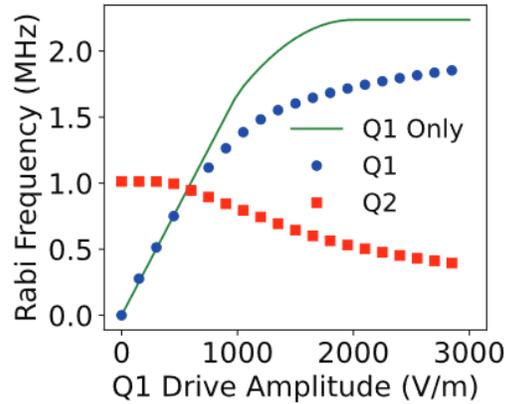
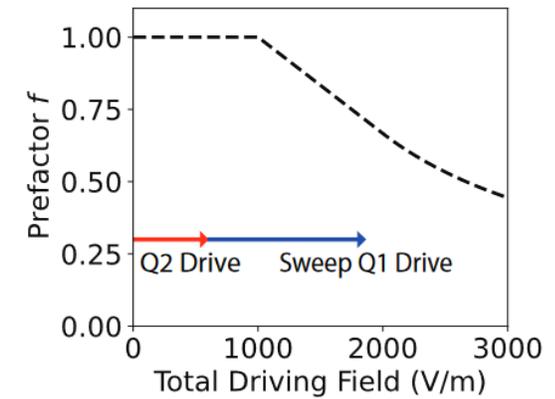
→ Captures saturation effect, but not full breadth of nonlinear features observed in experiment

# Phenomenological model (III)

- Electric driving term in  $H(t) = H_0 - \frac{E_Z}{2}\sigma_z + b'_{SL}\hat{x}\hat{n}\cdot\vec{\sigma} + E'_{ac}(t)\hat{x}$  is extended by prefactor:

$$E'_{ac}(t)\hat{x} \rightarrow f(P_k, \omega_k)E'_{ac}(t)\hat{x}$$

- Dependence on microwave power  $P_k$ , frequency  $\omega_k$
- Prefactor included: Rabi saturation + crosstalk as in experiment



Possible origins of nonlinearity:

- Electric drive distortion:** Driving on same gate gives different nonlinear response depending on which qubit is addressed  
 → Points to microscopic origin of nonlinearity (though, driving frequencies differ as well)
- Device heating:** Microwave drive may induce change to QD confinement, modifying orbital structure (e.g. via device strain or filling of charge traps)

# Summary

- Measurements of nonlinear Rabi frequency scaling and crosstalk effect
- EDSR Hamiltonian (harmonic&anharmonic confinement) doesn't capture full breadth of nonlinear effects
- Nonlinearity possibly caused by drive distortion and/or device heating
- Observed crosstalk poses a challenge for scaling via multiplexed qubit control